

(19)



Europäisches Patentamt

European Patent Office

Office européen des brevets



(11)

EP 0 885 983 A1

(12)

EUROPEAN PATENT APPLICATION

(43) Date of publication:

23.12.1998 Bulletin 1998/52

(51) Int. Cl.⁶: **C23C 16/30**

(21) Application number: **97201867.5**

(22) Date of filing: **19.06.1997**

(84) Designated Contracting States:

**AT BE CH DE DK ES FI FR GB GR IE IT LI LU MC
NL PT SE**

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(54) Method for coating a substrate with a diamond like nanocomposite composition

(57) The invention relates to a process for coating in a vacuum chamber a substrate at least in part with a diamond-like nanocomposite composition, comprising the steps of

- a) plasma etching of the substrate by bombardment of the substrate by ions of an inert gas such as Ar,
- b) introducing in the vacuum chamber, at a working pressure of between $5 \cdot 10^{-3}$ and $5 \cdot 10^{-2}$ mbar, a liquid organic precursor containing the elements C, H, Si, O to be deposited in suitable proportions, which proportions remain substantially constant during the deposition process,
- c) forming a plasma from the introduced precursor by an electron assisted DC-discharge using a filament with a filament current of 50-150 A, a negative filament bias DC voltage of 50-300 V and with a plasma current between 0.1 and 20 A,
- d) depositing the composition on the substrate, to which a negative DC-bias or negative RF self-bias voltage of 200 to 1200 V is applied, in order to attract ions formed in the plasma; the frequency of the RF voltage being comprised between 30 and 1000 kHz.

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Description

Field and Background of the Invention

The invention relates to a vacuum process for coating substrates with a diamond-like material, giving the substrate surfaces non-sticking properties, and making them i.a. very hard, corrosion and wear resistant and self-lubricating at the same time. The invention also relates to certain uses of substrates coated according to this method.

Diamond Like Nanocomposite (DLN) compositions consist of an amorphous random carbon network which is chemically stabilized by hydrogen atoms, interpenetrating with an amorphous glass-like silicon network which is chemically stabilized by oxygen atoms (a-C:H/a-Si:O).

In US patent 5352493 a process is described for coating a substrate with a DLN composition in a vacuum chamber. Thereby a plasma is formed from an organic precursor containing the elements C, H, Si and O to be deposited in a certain proportion. This composition is deposited from the plasma onto the substrate to which a negative DC-bias or RF self-bias voltage is applied.

Most of the conventionally applied deposition processes use high RF-voltage frequencies (up to 25 MHz, typically 13,56 MHz). This renders the upscaling of the process quite difficult.

Moreover, in some known processes very low pressures (less than $3 \cdot 10^{-4}$ mbar) are applied, making it difficult to apply a homogeneous coating, in particular on a substrate with a complex shape. It is however of great interest with regard to the industrial application of the homogeneous coatings - also on complex parts - to eliminate the need for very complex rotating substrate holders.

An improved DLN coating, deposition process, and reactor design are described in applicant's copending European patent applications Nos. 96201070 and 97200279.

Objects and Description of the Invention

It is an aim of the invention to provide a flexible process for uniformly coating any substrate with a non-sticking homogeneous DLN composition.

It is a further object of the invention to provide a coating method that ensures a good adherence of the coating onto the substrate, and that facilitates the upscaling to real industrial conditions.

The coating method according to the invention comprises the steps of

- a) plasma etching of the substrate by bombardment of the substrate by ions of an inert gas such as Ar (Reactive Ion Etching, RIE),
- b) introducing in the vacuum chamber, at a working pressure of between $5 \cdot 10^{-3}$ and $5 \cdot 10^{-2}$ mbar, a liq-

uid organic precursor containing the elements C, H, Si, O to be deposited in suitable proportions, which proportions remain substantially constant during the deposition process,

c) forming a plasma from the introduced precursor by an electron assisted DC-discharge using a filament with a filament current of 50-150 A, a negative filament bias DC voltage of 50-300 V and with a plasma current between 0.1 and 20 A,

d) depositing the composition on the substrate, to which a negative DC-bias or negative RF self-bias voltage of 200 to 1200 V is applied, in order to attract ions formed in the plasma; the frequency of the RF voltage being preferably comprised between 30 and 1000 kHz.

The plasma etching step a) of the proposed coating method activates the surface and removes residual oxides from it. This process step is essential for obtaining a good adherence of the coating onto the substrate.

The liquid organic precursor is preferably a siloxane compound such as hexamethyldisiloxane (HMDS), with a relatively high content of Si and O. A polyphenylmethylsiloxane, with a lower content of Si and O, can however also be used as precursor.

The use of a filament, e.g. a thoriated W filament, for forming the plasma by an electron assisted DC discharge, leads to a higher plasma density and thus to a deposition rate which is at least 20 % higher than that without use of the filament.

The bias voltage influences the properties of the deposited coatings, especially the hardness and the surface energy. The lower the bias voltage, the lower the hardness of the coating (e.g. 12 GPa at 500 V bias voltage, compared to 8 GPa at 300 V bias voltage), and the lower the surface energy. The non-sticking properties of the deposited coatings are indeed better when the coating is deposited at lower bias voltages.

The low RF frequency used in step d) of the proposed coating method facilitates its upscaling.

In a vacuum reactor as described in applicant's copending application 96201070 the precursor is introduced with Ar as a carrier gas. The mixture gas/precursor is delivered in a controllable manner to the vacuum chamber through a controlled evaporation mixing system. The liquid precursor is passed through a liquid mass flow controller to a mixing valve where it is combined with the carrier gas stream. From there it is transferred to a mixing chamber which is heated to about 80°C to 200°C. The precursor evaporates in the mixture and the hot mixture enters the vacuum chamber.

The working pressure is typically about $5 \cdot 10^{-3}$ to $5 \cdot 10^{-2}$ mbar, which is much higher than the pressures being applied in some known processes, favouring a more homogeneous deposition on complex substrates.

The non-sticking properties of the coating can be expressed in terms of its (low) surface energy and the (high) contact angle of a water droplet on it.

The contact angle of a water droplet on a surface coated with the DLN composition according to the proposed method, has been measured to be 90 to 95°. The surface energy of the deposited DLN coatings typically varies between 25 and 30 mN/m. The surface energy has been determined from the contact angles of certain liquids (demineralized water, formaldehyde, ethylene glycol, hexane) on the coated surface, using a Zisman plot.

In order to lower the surface energy of the deposited coating even more, additional oxygen gas can be added to the plasma during the coating process.

If a magnetic field between 5 and 150 Gauss is applied during the deposition of the coating, the plasma is intensified. The magnetic field can be applied e.g. by means of an inductive coil, situated near the thoriated filament in the reactor.

During the deposition process according to the invention, an inert gas can be introduced in the vacuum chamber, ionised and incorporated by ion bombardment of the growing layer. This may lead to a higher nanohardness of the deposited film. The inert gas can be introduced separately or as carrier gas for the precursor.

If desired, one or more transition metals can be codeposited by ion sputtering or by thermal evaporation in order to influence the heat and/or electrical conductivity of the coating.

An example of a coating composition deposited according to the proposed method is as follows: 36% Si, 17% O, and 47% C (leaving H out of consideration).

The non-sticking, homogeneous DLN coating displays a low surface energy, a high nanohardness, good tribological properties (even under humid conditions), and a controlled heat and/or electrical conductivity.

The coating can therefore be considered as a hard equivalent of teflon, having however a wear resistance far in excess of that of teflon. It is indeed a very important disadvantage of teflon that it is not hard enough to withstand strong mechanical forces. The proposed non-sticking DLN Coating has the additional advantage with respect to teflon that it does not contain any fluor.

The non-sticking properties of the deposited DLN coating, make it very suitable for many applications, i.e. for those as described in the following examples.

Examples

Example 1.

Hard Release Coating for Moulds Used in the Injection Moulding Process.

By means of the coating method according to the invention, a non-sticking DLN coating has been successfully applied onto the surface of a mould used for the injection moulding of polyoxymethylene (POM). The adherence of the coating to the substrate was very sat-

isfying, as were the demoulding results in general: no material stuck to the mould when releasing it. The release from the DLN coated mould was much faster than from the non-coated moulds, and no material deformation was observed when removing the moulded articles from the mould.

Example 2.

Release Coating for is An Electrode for Welding Nylon by Fusion

In the nylon welding process, two nylon muff-like workpieces are contacted at their ends with each other. A wire is inserted along and within the central cavity of these two pieces. The wire is then heated by induction or by means of electrical resistances (Joule effect), causing the nylon material in the contact area to melt. Afterwards, when starting to cool down, the wire is pulled out of the nylon workpieces. The nylon material solidifies upon cooling, so that the two workpieces are welded together.

The hot nylon material may in no way stick to the heating wire when pulling it out. This can be prevented by coating the wire with a non-sticking DLN film by means of the method according to the invention.

Commonly a teflon coating is used for this purpose. However, teflon cannot withstand the great mechanical (wear) forces acting on the coating when pulling it out of the cavity. As the tribological properties of the DLN coating are better than those of teflon, and as the DLN coating is much harder than the teflon equivalent, it is more suitable than teflon for this application. Indeed the DLN coated electrode is more durable and thus re-usable for a great number of times.

Example 3.

Non-Sticking Coating on Electro-Surgical Blades.

In one method for surgical cutting of the human skin or tissue use is made of an electro-surgical cutting blade. Thereby a RF voltage is applied to heat up said blade. The human body acts as the earth pole, so that an electrical current passes through the body, and burns skin or tissue open.

The coating method according to the invention can be used for depositing a non-sticking DLN coating onto the surface of the cutting blade, preventing human tissue or blood from sticking to it.

Various cutting tests were performed on liver and mozzarella cheese simulating the human tissue.

For the mozzarella cutting test a Valleytab Force2 ES generator and power control pencil were employed. The cheese was placed on the return electrode (metal plate) and the coated cutting blade was plugged into the pencil tip. A RF power of 25 W/500 kHz was applied.

The cutting results with respect to the DLN coated

blades are excellent. The coated blades perform at least as well as the commonly used teflon-coated ones.

Furthermore, the non-sticking DLN compositions show promising use as coatings on means for processing food, plastics and pharmaceuticals.

Claims

1. A process for coating in a vacuum chamber a substrate at least in part with a diamond-like nanocomposite composition, comprising the steps of
 - a) plasma etching of the substrate by bombardment of the substrate by ions of an inert gas such as Ar,
 - b) introducing in the vacuum chamber, at a working pressure of between $5 \cdot 10^{-3}$ and $5 \cdot 10^{-2}$ mbar, a liquid organic precursor containing the elements C, H, Si, O to be deposited in suitable proportions, which proportions remain substantially constant during the deposition process,
 - c) forming a plasma from the introduced precursor by an electron assisted DC-discharge using a filament with a filament current of 50-150 A, a negative filament bias DC voltage of 50-300 V and with a plasma current between 0.1 and 20 A,
 - d) depositing the composition on the substrate, to which a negative DC-bias or negative RF self-bias voltage of 200 to 1200 V is applied, in order to attract ions formed in the plasma; the frequency of the RF voltage being comprised between 30 and 1000 kHz.
2. A process according to claim 1, wherein the organic precursor is an organosilicon compound.
3. A process according to claim 2, whereby hexamethyldisiloxane is used as organic precursor.
4. A process according to claim 1, whereby during the deposition an inert gas is introduced in the vacuum chamber, ionised and incorporated by ion bombardment of the growing nanocomposite layer.
5. A process according to claim 1 wherein the precursor is mixed with a carrier gas for introduction in the vacuum chamber and the mixture is heated to evaporate the precursor.
6. A process according to claim 5 wherein the carrier gas comprises an inert gas.
7. A process according to claim 1, whereby at least one transition metal is codeposited in the composition layer by ion sputtering or by thermal evaporation.

8. A process according to claim 1 whereby the substrate is a mould used for injection moulding of polymer materials, which is coated at least in part with a non-sticking diamond-like nanocomposite composition.
9. A process according to claim 1 whereby the substrate is an electrode for welding nylon by fusion, which is coated at least in part with a non-sticking diamond-like nanocomposite composition.
10. A process according to claim 1 whereby the substrate is an electro-surgical cutting blade, which is coated at least in part with a non-sticking diamond-like nanocomposite composition.



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EUROPEAN SEARCH REPORT

Application Number
EP 97 20 1867

DOCUMENTS CONSIDERED TO BE RELEVANT			
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int.Cl.6)
X	WO 97 12757 A (ADVANCED REFRACTORY TECH) * page 16, line 29 - page 20, line 10 * * page 22, line 11 - line 20 * ---	1,2,7,10	C23C16/30
X Y	US 5 638 251 A (GOEL ARVIND ET AL) * column 9, line 34 - column 11, line 7 * ---	1,2,7 8,9	
Y	DORFMAN B ET AL: "DIAMOND-LIKE NANOCOMPOSITE COATINGS: NOVEL THIN FILMS" ADVANCES IN SCIENCE AND TECHNOLOGY. NEW DIAMOND AND DIAMOND-LIKE FILMS, vol. 6, 1995, pages 219-226, XP000602720 * paragraph 4-5 * ---	8,9	
A	WO 95 24275 A (DIAMONEX INC) * page 12, line 28 - page 14, line 18 * * page 17, line 11 - line 16 * ---	2-6	
A	DORFMAN V F: "DIAMOND-LIKE NANOCOMPOSITES (DLN)" THIN SOLID FILMS, vol. 212, no. 1 / 02, 15 May 1992, pages 267-273, XP000360223 * paragraph 3.6 * -----	1-10	
			TECHNICAL FIELDS SEARCHED (Int.Cl.6)
			C23C
The present search report has been drawn up for all claims			
Place of search THE HAGUE		Date of completion of the search 20 November 1997	Examiner Ekhult, H
CATEGORY OF CITED DOCUMENTS		T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons ----- & : member of the same patent family, corresponding document	
X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document			

